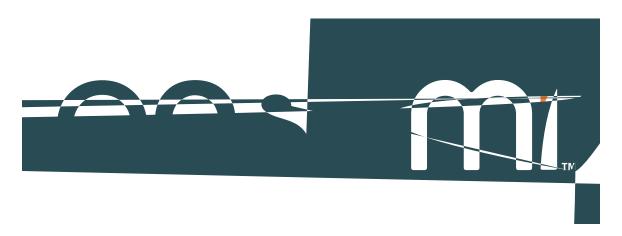
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#### **DATASHEET**

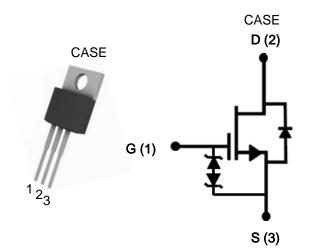
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#### Rev., J!2 <! 2000 OE

# UF3C065030T3S

#### Description

United



Part Number	Package	Marking
UF3C065030T3S	TO-220-3L	UF3C065030T3S















#### Maximum Ratings











#### Electrical Characteristics (T<sub>J</sub>





















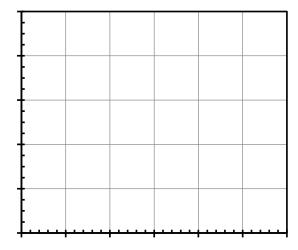


Figure 5. Typical drain-source on-resistances at  $\frac{1}{2}$  = 12V

Figure 6. Typical transfer characteristics at  $V_{S} = 5V$ 

Figure 7. Threshold voltage vs. junction temperature at  $V_{\text{DS}}$  = 5V and  $\frac{1}{b}$  = 10mA

Figure 8. Typical gate charge at  $\frac{1}{2}$ S = 400V and  $\frac{1}{6}$  = 50A





















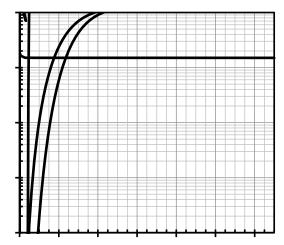


Figure 13. Typical capacitances at f = 100kHz and  $\frac{1}{2}$  = 0V

Figure 14. DC drain current derating

Figure 15. Total power dissipation

Figure 16. Maximum transient thermal impedance





















(a) (b)

(a) (b)

Figure 21. Clamped inductive switching turn-off energy including RC snubber energy loss (a) and RC snubber











(a) (b) Figure 22. Clamped inductive switching energy including RC snubber energy loss (a) and RC snubber energy I

(a)















# TO-220-3L PACKAGE OUTLINE, PART MARKING AND TUBE SPECIFICATIONS

### **PART MARKING**

#### **PACKING TYPE**

**ANTI-STATIC TUBE** 

**QUANTITY / TUBE: 50 UNITS** 

## **DISCLAIMER**

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